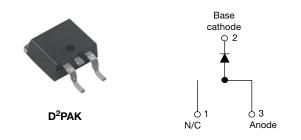
Vishay Semiconductors



High Performance Schottky Rectifier, 16 A



PRODUCT SUMMARY							
I _{F(AV)}	16 A						
V _R	35 V, 45 V						
V _F at I _F	0.57 V						
I _{RM}	40 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	24 mJ						
Package	TO-263AB (D ² PAK)						
Diode variation	Single die						

FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and gualified according to JEDEC[®]-JESD 47
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	16	А						
V _{RRM}		35/45	V						
I _{FSM}	t _p = 5 μs sine	1800	А						
V _F	16 A _{pk} , T _J = 125 °C	0.57	V						
TJ		-65 to 150	°C						

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBRB1635-M3 VS-MBRB1645-M3 UNITS								
Maximum DC reverse voltage	V _R	35	45	M				
Maximum working peak reverse voltage	V _{RWM}		45	v				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T_{C} = 134 °C, rated V_{R}	$T_{C} = 134 \text{ °C}$, rated V_{R}					
Non-repetitive peak surge current	IFSM	5 µs sine or 3 µs rect. pulse rated V _{RRM} applied		1800	А			
		Surge applied at rated load condition half wave single phase 60 Hz		150				
Non-repetitive avalanche energy	E _{AS}	T_J = 25 °C, I_{AS} = 3.6 A, L = 3.7 mH		24	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T_J max	3.6	А				

Revision: 03-Mar-14

Document Number: 94949

1 For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Measured lead from top of terminal to mounting plane

Vishay Semiconductors

8.0

10 000

UNITS

V

mΑ

рF

nΗ

V/µs

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES					
Maximum forward voltage drop	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63				
	VFM (*)	IOA	T _J = 125 °C	0.57				
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2				
reverse current	IRM \''	T _J = 125 °C	haled DC vollage	40				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	(test signal range 100 kHz to 1 MHz), 25 °C					

Rated V_R

Ls

dV/dt

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

Maximum voltage rate of change

Typical series inductance

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range		TJ		- 65 to 150	°C		
Maximum storage temperature range		T _{Stg}		- 65 to 175	U		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.50	- °C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
minimum				6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK	MBRE MBRE			



Vishay Semiconductors

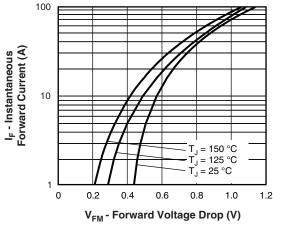
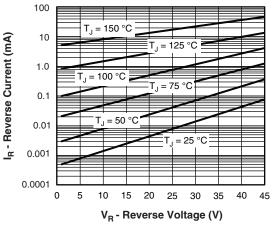
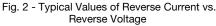


Fig. 1 - Maximum Forward Voltage Drop Characteristics





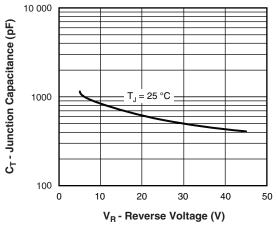


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

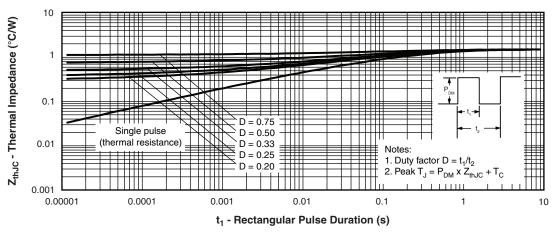
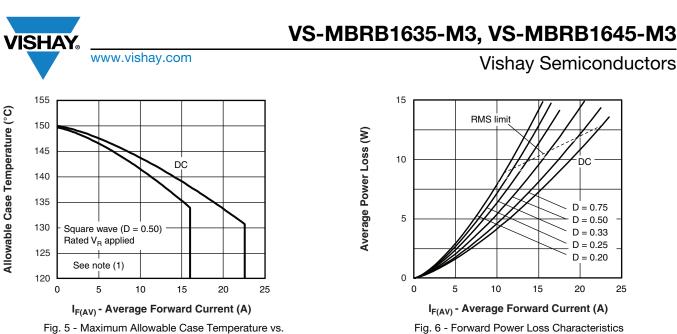


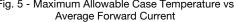
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

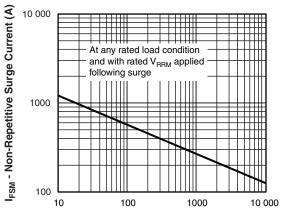
Revision: 03-Mar-14

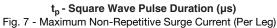
3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>









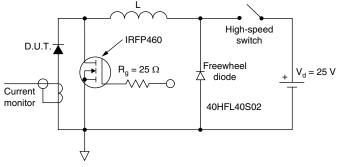


Fig. 8 - Unclamped Inductive Test Circuit

Note

Revision: 03-Mar-14

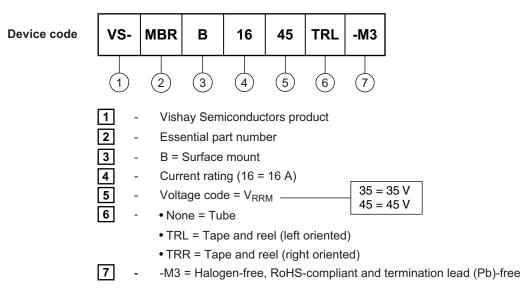
4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

ORDERING INFORMATION TABLE



ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBRB1635-M3	50	1000	Antistatic plastic tubes						
VS-MBRB1635TRR-M3	800	800	13" diameter reel						
VS-MBRB1635TRL-M3	800	800	13" diameter reel						
VS-MBRB1645-M3	50	1000	Antistatic plastic tubes						
VS-MBRB1645TRR-M3	800	800	13" diameter reel						
VS-MBRB1645TRL-M3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95046							
Part marking information	www.vishay.com/doc?95444						
Packaging information	www.vishay.com/doc?95032						
SPICE model	www.vishay.com/doc?95407						

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.